

View Online at <https://aerobasegroup.com/nsn/5961-00-504-0210>

Inclosure Material:

Glass

Overall Length:

0.213 inches

Overall Width:

0.320 inches

Component Name And Quantity:

2 semiconductor device diode

Mounting Method:

Press fit

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

70.0 reverse voltage, peak all semiconductor device diode

Current Rating Per Characteristic:

200.00 milliamperes forward current, average blank all semiconductor device diode and 500.00 milliamperes peak forward surge current
nanoamperes all semiconductor device diode

Power Rating Per Characteristic:

225.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

135.0 degrees celsius junction

Special Features:

Common anode; all semiconductor device diode junction pattern arrangement: pn

Terminal Type And Quantity:

3 ribbon

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fiig:

A110a0